

SANYO Semiconductors DATA SHEET

SCH1416-

N-Channel Silicon MOSFET General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱ _D		2	A
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	8	A
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=20V, VGS=0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	VDS=10V, ID=1A	0.84	1.4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=1A, VGS=10V		120	160	mΩ
	R _{DS} (on)2	ID=0.5A, VGS=4V		310	440	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		77		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		29		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		21		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		6.5		ns
Rise Time	tr	See specified Test Circuit.		3		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		10.5		ns
Fall Time	tf	See specified Test Circuit.		4.2		ns

Marking : KR

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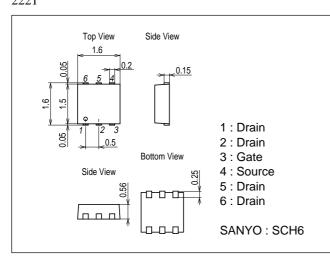
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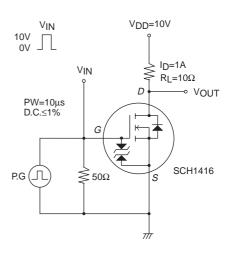
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Total Gate Charge	Qg	VDS=10V, VGS=10V, ID=2A		2.9		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =2A		0.7		nC
Gate-to-Drain "Miller" Charge	Qgd	VDS=10V, VGS=10V, ID=2A		0.4		nC
Diode Forward Voltage	VSD	IS=2A, VGS=0		0.88	1.2	V

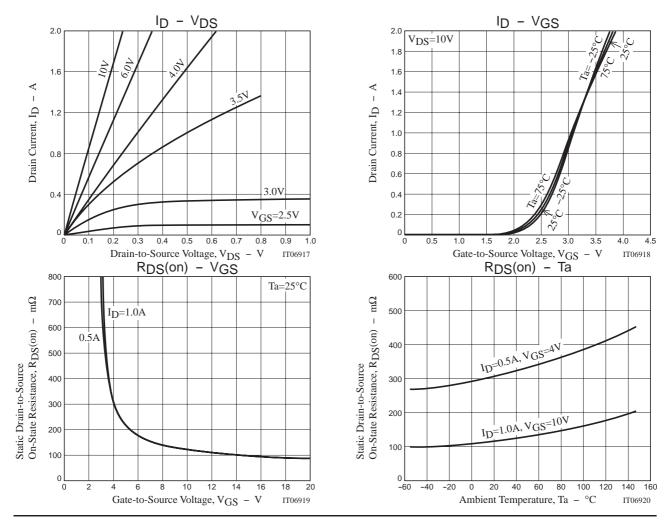
Package Dimensions

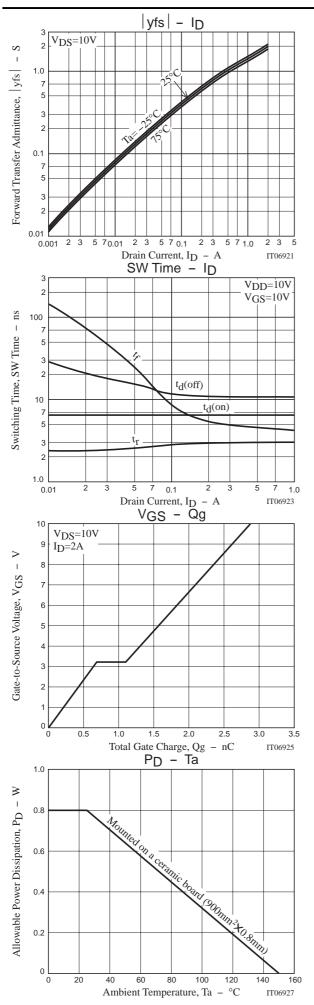
unit : mm 2221

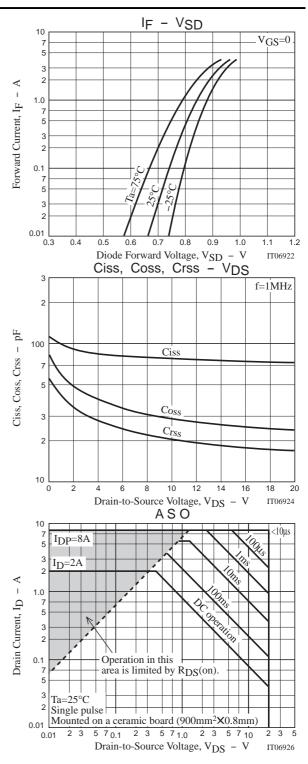


Switching Time Test Circuit









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